

# DN3019KT N-Channel MOSFET

### **General description**

N-Channel MOSFET

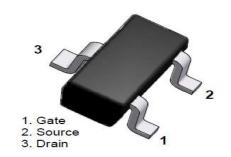
#### **FEATURES**

- Low On-resistance
- Fast Switching Speed
- Low Voltage Drive Makes This Device
- Ideal for Portable Equipment
- Easily Designed Drive Circuits
- Easy to Parallel
- RoHS Compliant & Green EMC
- Matte Tin(Sn) Lead Finish
- Weight: approx. 0.002g

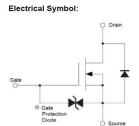
#### **Absolute Maximum Ratings** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$\mathbf{V}_{\mathtt{DS}}$	Drain-Source Voltage	30	V
$V_{GS}$	Continuous Gate-Source Voltage	±20V	V
ID	Continuous Drain Current	100	mA
P <sub>D</sub>	Power Dissipation	150	mW
Reja	Thermal Resistance from Junction to Ambient	833	°C /W
Тѕтс	Storage Temperature Range	-55 to +150	°C
Τυ	Operating Junction Temperature	+150	°C

### **Green Product**



SOT-523



Device Marking Code:



**Electrical Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified).

#### **Off Characteristics**

Symbol	Parameter	Test Condition	Limits			Unit
			Min	Тур	Max	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =10uA	30			Volts
Igss	Gate-Body Leakage	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±1	uA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	μA

# **DN3019KT**



### On Characteristics

Symbol	Parameter	Test Condition	Limits			11:4
			Min	Тур	Max	Unit
V <sub>th(GS)</sub>	Gate-Threshold Voltage	V <sub>DS</sub> = 3V, I <sub>D</sub> =100uA	0.8		1.5	Volts
RDS(on)	Drain-Source On-Resistance	V <sub>GS</sub> =4V, I <sub>D</sub> =10mA			8	Ω
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =1mA			13	Ω
<b>g</b> fs	Forward Trans Conductance	V <sub>DS</sub> =3V, I <sub>D</sub> =10mA	20			ms
VsD	Drain-Source Diode Forward Voltage	I <sub>S</sub> =115mA, V <sub>GS</sub> =0V			1.2	V

### **Dynamic Characteristics**

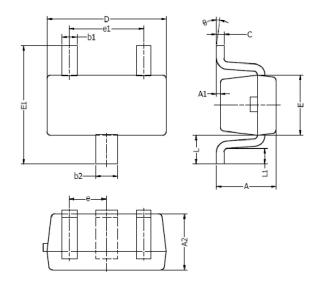
Symbol	Parameter	Test Condition	Limits			Unit
			Min	Тур	Max	Oille
Ciss	Input Capacitance	V <sub>DS</sub> = 5V V <sub>GS</sub> = 0V f		13		pF
Coss	Output Capacitance			9		pF
Crss	Reverse Transfer Capacitance	= 1.0MHz		4		pF

# **Switching Characteristics**

Symbol	Parameter	Test Condition	Limits			Unit
			Min	Тур	Max	John
<b>t</b> D(on)	Turn-on Time	V <sub>DD</sub> =5V, R <sub>L</sub> =500Ω,		15		nS
tD(off)	Turn-off Time	$I_D$ =10mA, $V_{Gs}$ =5V, $R_G$ = 10 $\Omega$		80		nS

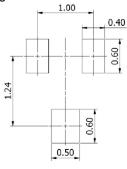


### **SOT-523 Package Outline**



DIM	MILLIMETERS		INCHES			
DIIVI	MIN	MAX	MIN	MAX		
A	0.70	0.90	0.028	0.035		
A1	0.00	0.10	0.000	0.004		
A2	0.70	0.80	0.028	0.031		
b1	0.15	0.25	0.006	0.010		
b2	0.25	0.35	0.010	0.014		
С	0.10	0.20	0.004	0.008		
D	1.50	1.70	0.059	0.067		
E	0.70	0.90	0.028	0.035		
E1	1.45	1.75	0.057	0.069		
е	0.50	0.50 TYP. 0.020 TYP		0.50 TYP.		TYP.
e1	0.90	1.10	0.035	0.043		
L	0.40 REF.		0.016 REF.			
L1	0.10	0.30	0.004	0.012		
θ	<b>0</b> °	8°	<b>0</b> °	8°		

#### **Typical Soldering Pattern:**



#### Note:

- 1. Above package outline conforms to JEITA EAIJ ED-7500A SC-75A.
- 2. Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.



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PSMN4R2-30MLD TK31J60W5,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 EFC2J004NUZTDG FCAB21350L1 P85W28HP2F7071 DMN1053UCP4-7 NTE2384 NTE2969 NTE6400A DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7
SSM6P54TU,LF DMP22D4UFO-7B IPS60R3K4CEAKMA1 DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 STU5N65M6
C3M0021120D DMN13M9UCA6-7 BSS340NWH6327XTSA1 MCM3400A-TP DMTH10H4M6SPS-13 IRF40SC240ARMA1
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